

2-Mbit serial I²C bus EEPROM with configurable device address, software write protection registers, and preprogrammed device address





SO8N (150 mil width) TSSOP8 (169 mil width)





UFDFPN8-DFN8 (2 x 3 mm)

WLCSP5 (CS and CP)



Unsawn wafer

Product status M24M02E-F



Features

I²C interface

- Compatible with the following I²C bus modes:
 - 1 MHz (Fast-mode Plus)
 - 400 kHz (Fast-mode)
 - 100 kHz (Standard-mode)

Memory

- 2-Mbit (256-Kbyte) of EEPROM
- Page size: 256-byte
- Additional 256-byte lockable identification page

Supply voltage

• Wide voltage range: 1.6 V to 5.5 V

Temperature

Operating temperature range: -40 °C to +85 °C

Fast write cycle time

• Byte and page write within 4 ms (typically 3.3 ms)

Performance

- Enhanced ESD/latch-up protection
- More than 4 million write cycles
- More than 200-year data retention
- Fast wake-up time (less than 5 μs)

Ultralow power current consumption

- 350 nA (typical) in standby mode
- 100 μA (typical) for read current
- 500 μA (typical) for write current

Advanced features

- Configurable device address register
- Device type identifier register (read-only)
- Preprogrammed device address
- Software write protection register
- Hardware write protection of the whole memory array
- · Random and sequential read modes

Packages

SO8N, TSSOP8, UFDFPN8, and WLCSP5 (ECOPACK2-compliant)



1 Description

The M24M02E-F is a 2-Mbit I 2 C-compatible EEPROM (electrically erasable programmable memory) organized as 256 K × 8 bits. It can operate with a supply voltage from 1.6 V to 5.5 V with a clock frequency up to 1 MHz, over an ambient temperature range of -40 $^\circ$ C to +85 $^\circ$ C.

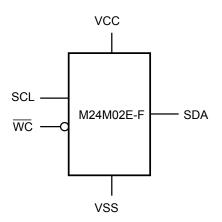
The device offers three 8-bit registers, namely: the device type identifier (DTI) register, the configurable device address (CDA), and the software write protection (SWP) register.

The device offers an additional 256-byte page, called the identification page. This page can be used to store sensitive application parameters, which can later be permanently locked in read-only mode.

The M24M02E-F is available in the standard 8-pin TSSOP8, SO8N, UFDFPN8, and in the 5-ball wafer level chip scale packaging (WLCSP) with the \overline{WC} pin.

On demand, the EEPROM can be delivered with a preprogrammed and locked device address.

Figure 1. Logic diagram



1100073

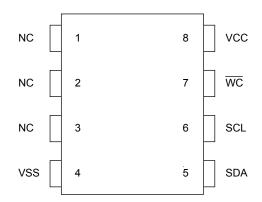
Table 1. Signal names

Signal name	Function	Direction
SDA	Serial data	I/O
SCL	Serial clock	Input
WC	Write control	Input
V _{CC}	Supply voltage	-
V _{SS}	Ground	-

DS14157 - Rev 3 page 2/55



Figure 2. 8-pin package connections, top view

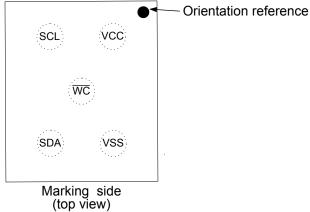


DT76092V2

DT76098V1

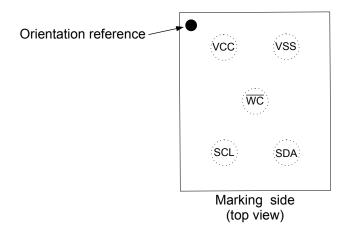
- 1. NC: Not connected.
- 2. Refer to Section 10: Package information for package dimensions, and how to identify pin 1.

Figure 3. 5-ball package connection - WLCSP (CS)



- 1. Drawing is not to scale.
- 2. Refer to Section 10.4: WLCSP5 (CS) with BSC package information for mechanical data and outline details.

Figure 4. 5-ball package connection- WLCSP (CP)



DT76099V1

- 1. Drawing is not to scale.
- 2. Refer to Section 10.5: WLCSP5 (CP) with BSC package information for mechanical data and outline details.



2 Signal description

2.1 Serial clock (SCL)

SCL is an input. The signal applied on it is used to strobe the data available on SDA(in) and to output the data on SDA(out).

2.2 Serial data (SDA)

SDA is an input/output used to transfer data in or out of the device. SDA(out) is an open-drain output that can be wired-AND with other open-drain or open-collector signals on the bus. A pull-up resistor must be connected from serial data (SDA) to V_{CC} (Figure 26 and Figure 27 indicate how to calculate the value of the pull-up resistor).

2.3 Write control (\overline{WC})

This input signal is useful for protecting the whole content of the memory from inadvertent write operations. Write operations are:

- Disabled to the whole memory array when write control is driven high.
- Enabled when write control is either driven low or left floating.

When the write control signal is driven high, the device select and address bytes are acknowledged, but data bytes are not acknowledged.

V_{SS} (ground)

V_{SS} is the reference for the V_{CC} supply voltage.

2.5 Supply voltage (V_{CC})

2.5.1 Operating supply voltage (V_{CC})

Before selecting the memory and issuing instructions to it, a valid and stable V_{CC} voltage within the specified $[V_{CC}(min), V_{CC}(max)]$ range must be applied (see operating conditions in Section 9: DC and AC parameters).

To secure a stable DC supply voltage, it is recommended to decouple the V_{CC} line with a suitable capacitor (usually from 10 nF to 100 nF) close to the V_{CC}/V_{SS} package pins.

This voltage must remain stable and valid until the end of the transmission of the instruction and, for a write instruction, until the completion of the internal write cycle (t_W) .

2.5.2 Power-up conditions

The V_{CC} voltage increases from 0 V up to the minimum V_{CC} operating voltage (see operating conditions in Section 9: DC and AC parameters). Once V_{CC} is greater than or equal to the minimum V_{CC} level, the controller must wait for at least t_{WU} before sending the first command to the device. See Table 19. AC characteristics in Fast-mode and Table 20. AC characteristics in Fast-mode Plus for the value of the wake-up time parameter.

2.5.3 Device reset

To prevent inadvertent write operations during power-up, a power-on reset (POR) circuit is included. At power-up, the device does not respond to any instruction until V_{CC} has reached the internal reset threshold voltage. This threshold is lower than the minimum V_{CC} operating voltage (see operating conditions in Section 9: DC and AC parameters). When V_{CC} passes over the POR threshold, the device is reset and enters the standby power mode. The device must not be accessed until V_{CC} reaches a valid and stable DC voltage within the specified [V_{CC} (min), V_{CC} (max)] range (see operating conditions in Section 9: DC and AC parameters). Similarly, during power-down, when the V_{CC} decreases, the device must not be accessed once V_{CC} drops below V_{CC} (min). When V_{CC} drops below the power-on-reset threshold voltage, the device stops responding to any instruction sent to it.

DS14157 - Rev 3 page 4/55



2.5.4 Power-down conditions

During power-down, when the V_{CC} decreases to 0, the device must be in the standby power mode (the mode is reached after decoding a stop condition, with no internal write cycle in progress).

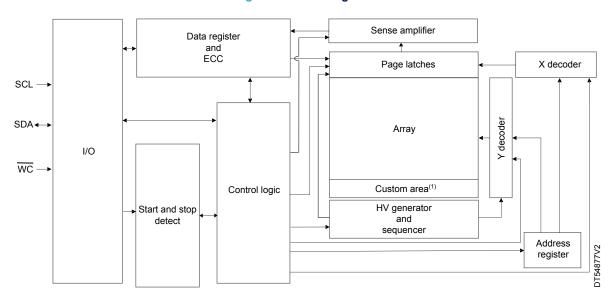
DS14157 - Rev 3 page 5/55



3 Memory organization

The memory is organized as shown below.

Figure 5. Block diagram



1. DTI, CDA, SWP registers and identification page.

DS14157 - Rev 3 page 6/55



4 Device features

4.1 Device type identifier register (DTI)

The device type identifier register (DTI) is an 8-bit register permanently locked in read-only mode. This register is factory programmed with device type identifier bits (DTI3, DTI2, DTI1, and DTI0) set to 1011 and with device type identifier lock bit (DTIL) set to 1 to freeze definitively the register. DTI3, DTI2, DTI1, and DTI0 defines the device type identifier address in the device select code. At power-up, the device loads the last configuration of DTI3, DTI2, DTI1, DTI0, and DTIL values.

This register is read by issuing the read device type identifier instruction. This instruction uses the same protocol and format as the random address read (from the memory array) except for the following differences (refer to Table 9, Table 10, and Table 11).

- Device type identifier = 1011
- MSB address bits A15, A14, and A13 must be equal to 111
- MSB address bits from A12 to A8 are don't care
- LSB address bits from A7 to A0 are don't care

The description of the device type identifier register is given in Table 2.

Table 2. Device type identifier register

bit 7	bit 6	bit5	bit4	bit3	bit2	bit1	bit0
DTI3 = 1	DTI2 = 0	DTI1 = 1	DTI0 = 1	X ⁽¹⁾	X	X	DTIL = 1

1. X = Don't care bit. Read as 0.

Note: The factory default value is 10110001.

Table 3. Device type identifier register description

Bit	Function
	DTI3, DTI2, DTI1, DTI0: Device type identifier bits.
b7 to b4	b7, b6, b5, b4 are used to configure the device type identifier of the device select code.
	• (b7, b6, b5, b4) = (1, 0, 1, 1) the device type identifier is 1011 (factory default value)
	Note: Bits b7 to b4 are frozen at factory delivery.
b3 to b1	Reserved bits. Read as 0. (b3, b2, b1) = (0, 0, 0)
	DTIL: Device type identifier lock bit.
b0	b0 indicates that the DTI register status is in read-only mode.
bu	• (b0) = (1) the device type identifier lock bit is equal to 1 (factory default value)
	Note: Bit b0 is frozen at factory delivery.

DS14157 - Rev 3 page 7/55



4.2 Configurable device address register (CDA)

The CDA is an 8-bit register allowing the user to define a configurable device address (C2), and includes a specific bit, named device address lock (DAL), to permanently freeze the configurable device address register. This register can be read and written by issuing the read or write configurable device address instruction. These instructions use the same protocol and format as the random address read or page write (from/into memory array) except for the following differences (refer to Table 9, Table 10, and Table 11):

- Device type identifier = 1011
- MSB address bits A15, A14, and A13 must be equal to 110
- MSB address bits from A12 to A8 are don't care
- LSB address bits from A7 to A0 are don't care

C2 and DAL are defining the chip enable address in the device select code and the device address lock. These bits can be written and reconfigured with a write command.

At power-up or after reprogramming, the device loads the last configuration of C2, and DAL values. To prevent unwanted change of configurable device address bits, the M24M02E-F protects the CDA register permanently freezing it in read-only mode. The update of the CDA register is disabled (read-only) when the DAL bit is set to 1 (DAL = 1).

In the same way, the update of the CDA register is enabled when the DAL bit is set to 0 (DAL = 0). Sending more than one byte during a write configurable device address command aborts the write cycle (CDA register content does not change).

Note:

- Updating the DAL bit from 0 to 1 is an irreversible action: the C2, and DAL bits cannot be updated anymore.
- If the write control input (WC) is driven high, or if the DAL bit is set to 1 the write configurable device address command is not executed, the accompanying data byte is not acknowledged, as shown in Figure 7, and the write cycle does not start.

The description of the configurable device address register is given in Table 4.

Table 4. Configurable device address register

bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
X ⁽¹⁾	Х	Х	Х	C2	Х	Х	DAL

1. X = Don't care bits. Read as 0.

Note:

The factory default value is 00000000.

For devices delivered with preprogrammed device address:

- The default value of C2 is given in Table 6. Preprogrammed device address.
- DAL is set to 1

Table 5. Configurable device address register description

Bit	Function
b7 to b4, b2, and b1	Don't care bits. Read as 0.
57 to 54, 52, and 51	(b7, b6, b5, b4, b2, b1) = (0, 0, 0, 0, 0, 0)
	C2: Configurable device address bit.
b3	b3 is used to configure up to two possibilities of chip enable address:
	• b3 = 0: the chip enable address is 0
	b3 = 1: the chip enable address is 1
	DAL: Device address lock bit.
	b0 locks the CDA register in read-only mode:
b0	• b0 = 0: bits b3 and b0 can be modified
	• b0 = 1: bits b3 and b0 cannot be modified and therefore the CDA register is frozen
	Note: Bits b3 and b0 can be updated (if b0 = 0) in the same write instruction. Setting b0 from 0 to 1 is an irreversible action.

DS14157 - Rev 3 page 8/55



If the M24M02E-F is delivered with the preprogrammed device address, the configurable device address register becomes locked at factory delivery and can only be read. The bit C2 is set as specified in Table 6. Preprogrammed device address, and the DAL bit is set to 1.

The corresponding commercial product number with the preprogrammed device address and availability are given in Table 6

Table 6. Preprogrammed device address

Commercial product number ⁽¹⁾	Device address C2	Availability ⁽²⁾
M24M02E-Fxx6T1	1	On demand

- 1. xx in the part number varies by package.
- 2. The product might not be available in all packages. For more information, contact your nearest ST sales office.

4.3 Software write protection register (SWP)

The software write protection (SWP) register is a nonvolatile 8-bit register that allows the user to protect a specific area of the memory against the write instruction. The SWP offers four nonvolatile bits for user configuration:

- Two bits for setting the size of the write-protected memory, identified as the block protection bits (BP0, BP1).
- One bit to enable or disable the write protection of the desired area, identified as the write protect activation (WPA) bit.
- One bit to definitively freeze the SWP register in read-only mode, identified as the write protection lock (WPL) bit.

This register can be read and written by issuing the read or write software write protection register instructions. These instructions use the same protocol and format as the random address read or page write (from/into memory array) except for the following differences (refer to Table 9, Table 10, and Table 11:

- Device type identifier = 1011
- MSB address bits A15, A14, and A13 must be equal to 101
- MSB address bits from A12 to A8 are don't care
- LSB address bits from A7 to A0 are don't care

BP1 and BP0 are the block protection bits. WPL is the write protect lock bit and WPA is the write protect activation bit. These bits can be written and reconfigured with a write command. At power-up, the device loads the last configuration of the SWP register value.

The user can update the SWP register as often as the WPL bit stays at 0. Writing more than one byte discard the write cycle (software write protection register content is not changed).

To prevent unwanted change of software write protection register bits, the M24M02E-F protects the SWP register, freezing it permanently in read-only mode. The update of the SWP register is disabled (read only) when the WPL bit is set to 1 (WPL = 1). In the same way, the update of the SWP register is enabled when the WPL bit is set to 0 (WPL = 0).

When the WPL is set to 1 and writing to the software write protection register, the device select and address bytes are acknowledged. However, the data byte is not acknowledged, and the write cycle does not start.

Note:

- Updating the WPL bit from 0 to 1 is an irreversible action: the WPA, BP1, BP0, and WPL bits cannot be updated any more
- If the write control input (WC) is driven high or if the WPL bit is set to 1, the write command on the software write protection register is not executed and the accompanying data byte is not acknowledged, as shown in Figure 12. Write SWP register (data write inhibited by software or hardware).

The description of the software write protection register is given in the following table:

Table 7. Software write protection register values

bit 7	bit 6	bit 5	bit 4	bit 3	bit 2	bit 1	bit 0
X ⁽¹⁾	X	Х	X	WPA	BP1	BP0	WPL

1. X = Don't care bits. Read as 0.

Note: The factory default value is 00000000.

DS14157 - Rev 3 page 9/55



Table 8. Software write protection register description

Bit	Function
b7 to b4	• Don't care bits. Read as 0. (b7, b6, b5, b4) = (0, 0, 0, 0)
	WPA: Write protect activation bit.
b3	b3 enables or disables the write protection:
	• b3 = 0: no write protection. The whole memory can be written.
	• b3 = 1: write protection active. The memory block is protected according to BP bits setting.
	BP1, BP0: block protection bits
	b2 and b1 define the size of the memory block to be protected against write instruction:
b2 to b1	• (b2, b1) = (0, 0): the upper quarter of memory is write-protected
	• (b2, b1) = (0, 1): the upper half of memory is write protected
	 (b2, b1) = (1, 0): the upper ³/₄ of memory is write protected (b2, b1) = (1, 1): the whole memory is write protected
	(82, 81) (1, 1). the whole memory is write protested
	WPL: write protection lock bit
	b0 locks the write protection register value.
b0	• b0 = 0: bits [b3: b0] can be modified
	• b0 = 1: bits [b3: b0] cannot be modified and the write protection register is frozen.
	Note: bits b3 to b0 can be updated (if b0 = 0) in the same write instruction. Setting b0 from 0 to 1 is an irreversible action.

4.4 Identification page

The identification page (256-byte) is an additional page that can be read or written and can later be permanently locked in read-only mode. It is read or written by issuing the read or write identification page instruction. These instructions use the same protocol and format as the random address read or page write (from memory array) except for the following differences (refer to Table 9, Table 10, and Table 11):

- Device type identifier = 1011
- MSB address bits A15, A14, and A13 must be equal to 000
- MSB address bits from A12 to A8 are don't care
- LSB address bits from A7 to A0 define the byte address inside the identification page

If the identification page is locked, the data bytes transferred during the write identification page instruction are not acknowledged (NO ACK).

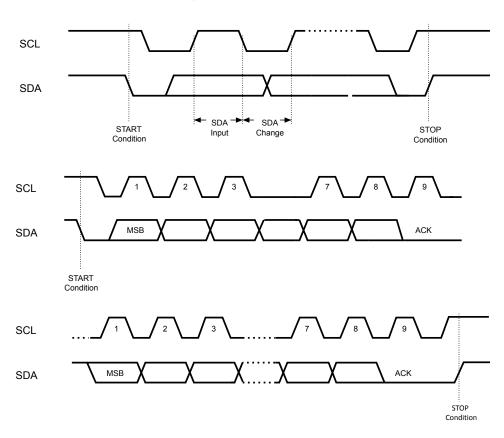
The identification page is filled with all bytes written to FFh.

DS14157 - Rev 3 page 10/55

5 Device operation

The device supports the I²C protocol summarized in Figure 6. Any device that sends data onto the bus is defined as a transmitter, and any device that reads the data is defined as a receiver. The device that controls the data transfer is known as the bus controller, and the other as the target. A data transfer can only be initiated by the bus controller, which also provides the serial clock for synchronization. The device is always a target in all communications.

Figure 6. I²C bus protocol



50012V1



5.1 Start condition

The start condition is identified by a falling edge of serial data (SDA) while the serial clock (SCL) is stable in the high state. This condition must precede any data transfer instruction. The device continuously monitors the SDA and SCL for a start signal, except during a write cycle.

5.2 Stop condition

The stop condition is identified by a rising edge of serial data (SDA) while the serial clock (SCL) is stable in the high state. This condition terminates the communication between the device and the bus controller. A read instruction followed by NO ACK can be followed by a stop condition to force the device into the standby mode. A stop condition at the end of a write instruction triggers the internal write cycle.

5.3 Data input

During data input, the device samples the serial data (SDA) on the rising edge of the serial clock (SCL). For proper device operation, the SDA must be stable during the rising edge of the SCL, and the SDA signal must change only when the SCL is driven low.

5.4 Acknowledge bit (ACK)

The acknowledge bit is used to indicate a successful byte transfer. The bus transmitter, whether a bus controller or target device, releases serial data (SDA) after sending eight bits of data. During the ninth clock pulse period, the receiver pulls SDA low to acknowledge the receipt of the eight data bits.

DS14157 - Rev 3 page 12/55



5.5 Device addressing

To start communication between the bus controller and the target device, the bus controller must initiate a start condition. Following this and unless the product is delivered with the pre-programmed device address the bus controller sends the device select code and byte address as specified in Table 9, Table 10, and Table 11. When the device select code is received, the device responds only if the bit b3 value matches the value of the C2 bit programmed in the configurable device address register.

If a match occurs, the corresponding device gives an acknowledgment on serial data (SDA) during the ninth bit time. If the device does not acknowledge the device select code, it deselects itself from the bus and goes into standby mode after a stop condition.

The eighth bit is the read/write bit (\overline{RW}). This bit is set to 1 for read and 0 for write operations. The 256-Kbyte (2-Mbit) are addressed with 18 address bits, the 16 lower address bits being defined by the two address bytes and the most significant address bit (A17 and A16) being included in the device select code (see Table 9).

Features	Device typ	e ident	tifier bi	its	Chip enable address bits ⁽¹⁾ Address			bit RW	
reatures	Bit 7 (MSB) ⁽²⁾	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0 (LSB)	
Memory	1	0	1	0	C2	A17	A16	R₩	
Device type identifier	1	0	1	1	C2	Х	X ⁽³⁾	R₩	
Configurable device address	1	0	1	1	C2	Х	Х	R₩	
Software write protection	1	0	1	1	C2	Х	Х	R₩	
Identification page	1	0	1	1	C2	Х	Х	R₩	
Identification page lock	1	0	1	1	C2	Х	Х	R₩	

Table 9. Device select code

- 1. C2 is compared with the value read on bit b3 of the CDA register.
- 2. The most significant bit, b7, is sent first.
- 3. X = Don't care bit

Table 10. First byte address

Features	Bit 7 (MSB) ⁽¹⁾	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0 (LSB)
Memory	A15	A14	A13	A12	A11	A10	A9	A8
Device type identifier	1	1	1	X ⁽²⁾	Х	Х	Х	X
Configurable device address	1	1	0	Х	Х	Х	Х	Х
Software write protection	1	0	1	Х	Х	Х	Х	Х
Identification page	0	0	0	Х	Х	Х	Х	Х
Identification page lock	0	1	1	Х	Х	Х	Х	Х

- 1. The most significant bit, b7, is sent first.
- 2. X = Don't care bit.

DS14157 - Rev 3 page 13/55



Table 11. Second byte address

Features	Bit 7 (MSB) ⁽¹⁾	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0 (LSB)
Memory	A7	A6	A5	A4	А3	A2	A1	A0
Device type identifier	X ⁽²⁾	Х	Х	Х	Х	Х	Х	Х
Configurable device address	X	Х	Х	Х	Х	Х	Х	Х
Software write protection	X	Х	Х	Х	Х	Х	Х	Х
Identification page	A7	A6	A5	A4	A3	A2	A1	A0
Identification page lock	X	Х	Х	Х	Х	Х	Х	Х

^{1.} The most significant bit, b7, is sent first.

DS14157 - Rev 3 page 14/55

^{2.} X = Don't care bit



6 Instructions

6.1 Write operations on memory array

Following a start condition the bus controller sends a device select code with the R/W bit $(R\overline{W})$ reset to 0. The device acknowledges this, as shown in Figure 7, and waits for two address bytes. The device responds to each address byte with an acknowledge bit, and then waits for the data byte. See Table 9, Table 10, and Table 11 how to address the memory array. The 256-Kbyte (2-Mbit) are addressed with 18 address bits, the 16 lower address bits being defined by the two address bytes and the most significant address bit (A17 and A16) being included in the device select code (see Table 9).

When the bus controller generates a stop condition immediately after a data byte ACK bit (in the tenth bit time slot), either at the end of a byte write or a page write, the internal write cycle t_W is triggered. A stop condition at any other time slot does not trigger the internal write cycle.

After the stop condition and the successful completion of an internal write cycle (t_W), the device internal address counter is automatically incremented to point to the next byte after the last modified byte.

During the internal write cycle, serial data (SDA) is disabled internally, and the device does not respond to any requests.

If the addressed area is write protected by software through the SWP setting or hard protected through \overline{WC} pin driven high, the write instruction is not executed and the accompanying data bytes are not acknowledged, as shown in Figure 8.

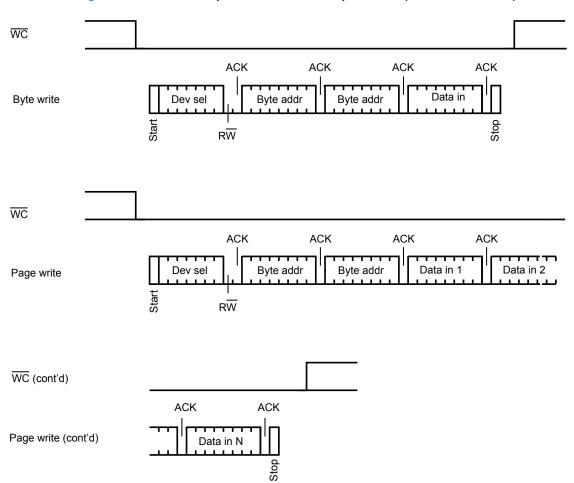
DS14157 - Rev 3 page 15/55



6.1.1 Byte write

After the device select code and the address bytes, the bus controller sends one data byte. If the addressed location is write-protected, through the SWP setting or through the \overline{WC} pin being driven high, the device replies with NO ACK, and the location is not modified. If the addressed location is not write-protected, the device replies with ACK. The bus controller terminates the transfer by generating a stop condition, as shown in Figure 7.

Figure 7. Write mode sequences without write protection (data write enabled)



DT01106dV2



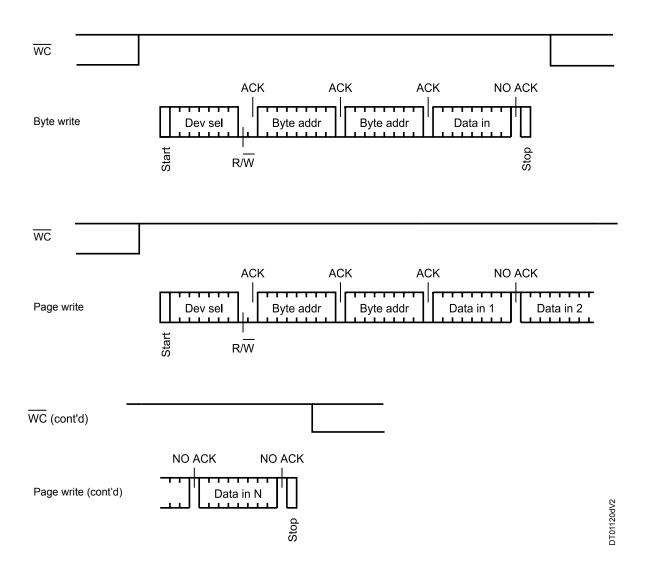
6.1.2 Page write

Using this mode it is possible to write up to 256 bytes in a single write cycle, provided they are all located on the same page. This means that the most significant memory address bits, from A17 to A8, are the same. If more bytes are sent than fit up to the end of the page, a roll-over occurs: the bytes exceeding the page end are written on the same page, from location 0.

The bus controller sends from 1 to 256 bytes of data, each of which is acknowledged by the device if the addressed bytes are not write-protected through the SWP setting or through WC pin (driven low). In the opposite case, when the addressed bytes are write-protected by SWP setting or WC pin (driven high), the contents of the addressed memory location are not modified, and each data byte is followed by a NO ACK, as shown in Figure 8. After each transferred byte, the internal page address counter is incremented.

The transfer is terminated when the bus controller generates a stop condition.

Figure 8. Write mode sequences with write protection (data write inhibited)



DS14157 - Rev 3 page 17/55



6.2 Write operations on registers, identification page, and minimizing delays

6.2.1 Write operation on DTI register

Write operations on the device type identifier (DTI) register are not allowed.

The register is delivered locked in read-only.

6.2.2 Write operation on CDA register

Write operations on the configurable device address register are performed according to the state of the device address lock bit (DAL) or the status of the \overline{WC} line.

If the configurable device address register is write protected by software with DAL = 1 or hard protected with \overline{WC} line driven high, the write operation on this register is not executed and the accompanying data byte is not acknowledged as shown in Figure 10.

Following a start condition the bus controller sends a device select code with the R/W bit $(R\overline{W})$ set to 0. The device acknowledges this, as shown in Figure 9, and waits for the address bytes where the register is located. The device responds to each address byte with an acknowledge bit, and then waits for the data byte. See in Table 9, Table 10, and Table 11 how to address the configurable device address register.

When the bus controller generates a stop condition immediately after the data byte ACK bit (in the tenth bit time slot), the internal write cycle t_W is triggered. A stop condition at any other time slot does not trigger the internal write cycle.

During the internal write cycle, serial data (SDA) is disabled internally, and the device does not respond to any requests (NO ACK).

If the bit C2 has been reconfigured with a correct write command, the device acknowledges if the chip enable address of the device select code is equal to the new value of C2, otherwise no ACK. Sending more than one byte aborts the write cycle (configurable device address content does not change). Bits (C2, DAL) can be updated (DAL = 0 to 1) in the same program instruction.

Figure 9. Write CDA register (data write enabled)

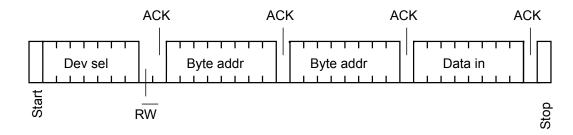
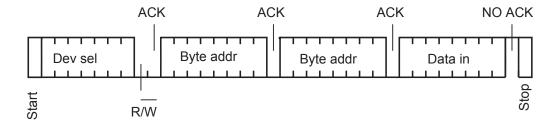


Figure 10. Write CDA register (data write inhibited by software or hardware)



T67286V1

JT67285V

DS14157 - Rev 3

Instructions



6.2.3 Write operation on SWP register

Write operations on SWP register are performed according to the state of the write protect lock bit (WPL) or to the status of the \overline{WC} line.

Following a start condition the bus controller sends a device select code with the R/W bit $(R\overline{W})$ set to 0. The device acknowledges this, as shown in Figure 11, and waits for the address bytes where the SWP register is located. The device responds to each address byte with an acknowledge bit, and then waits for the data byte. See in Table 9, Table 10, and Table 11 how to address the software write protection register.

When the bus controller generates a stop condition immediately after the data byte ACK bit (in the tenth bit time slot), the internal write cycle t_W is triggered. A stop condition at any other time slot does not trigger the internal write cycle.

During the internal write cycle, serial data (SDA) is disabled internally, and the device does not respond to any requests (NO ACK).

Sending more than one byte aborts the write cycle (software write protection register content is not changed). If the SWP register is already locked or hard write protected with \overline{WC} line driven high, the write operation is not executed and the accompanying data byte is not acknowledged as shown in Figure 12.

Figure 11. Write SWP register (data write enabled)

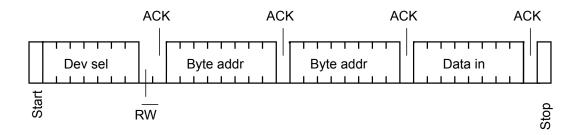
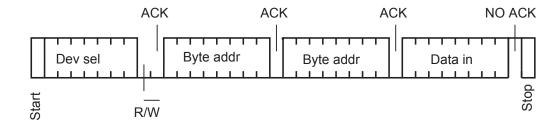


Figure 12. Write SWP register (data write inhibited by software or hardware)



JT67286V1

JT67285V

DS14157 - Rev 3 page 19/55

6.2.4 Write operation on identification page

Write operations on the identification page are performed according to the state of the \overline{WC} line or to the lock/ unlock status. Following a start condition the bus controller sends a device select code with the R/W bit (\overline{RW}) set to 0. The device acknowledges this, as shown in Figure 13, and waits for the address bytes where the identification page is located. The device responds to each address byte with an acknowledge bit, and then waits for the data byte. See Table 9, Table 10 and Table 11 how to address the identification page.

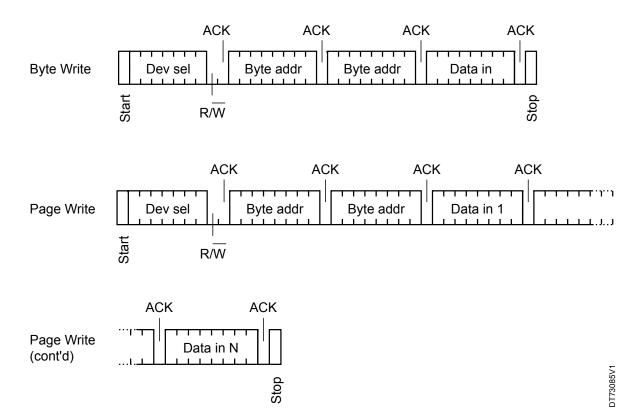
When the bus controller generates a stop condition immediately after the data byte ACK bit (in the tenth bit time slot), the internal write cycle t_W is triggered. The device internal address counter is automatically incremented to point to the next byte after the last modified byte.

A stop condition at any other time slot does not trigger the internal write cycle.

During the internal write cycle, serial data (SDA) is disabled internally, and the device does not respond to any requests (NO ACK).

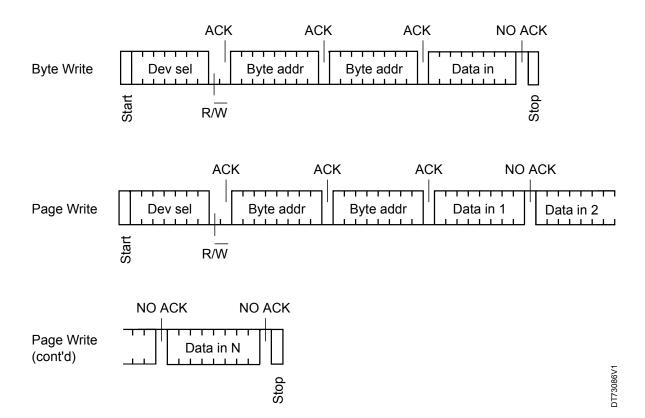
If the identification page is already locked in read-only mode (lock status) or hard write protected with \overline{WC} line driven high, the write operation on the identification page is not executed and the accompanying data bytes are not acknowledged as shown in Figure 14. Write identification page (page locked or hard protected).

Figure 13. Write identification page (page unlocked)



DS14157 - Rev 3 page 20/55

Figure 14. Write identification page (page locked or hard protected)



DS14157 - Rev 3 page 21/55



6.2.5 Lock operation on identification page

The lock identification page instruction (lock ID) permanently locks the identification page in read-only mode.

Following a start condition the bus controller sends a device select code with the R/W bit $(R\overline{W})$ set to 0. The device acknowledges this, as shown in Figure 15, and waits for the address bytes where the identification page is located. The device responds to each address byte with an acknowledge bit, and then waits for a specific data byte value. See Table 9, Table 10, and Table 11 how to address the identification page.

The data byte must be equal to the binary value xxxx xx1x, where x is don't care.

When the bus controller generates a stop condition immediately after the data byte ACK bit (in the tenth bit time slot), the internal write cycle t_W is triggered. A stop condition at any other time slot does not trigger the internal write cycle.

During the internal write cycle, serial data (SDA) is disabled internally, and the device does not respond to any requests (NO ACK).

If the identification page is already locked or hard write protected with \overline{WC} line driven high, the write operation is not executed and the accompanying data bytes are not acknowledged as shown in Figure 16.

Figure 15. Lock operation on identification page (unlocked or data write enabled)

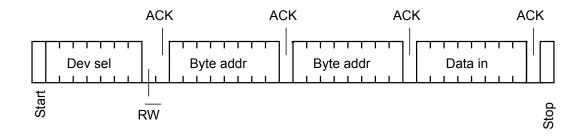
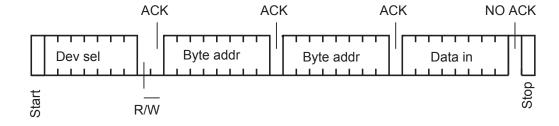


Figure 16. Lock operation on identification page (already locked or data write inhibited by hardware)



1.79871

JT67285V

DS14157 - Rev 3 page 22/55

Instructions

JT01847eV1



6.2.6 Minimizing write delays by polling on ACK

During the internal write cycle, the device disconnects itself from the bus, and writes a copy of the data from its internal latches to the memory cells. The maximum write time (t_w) is shown in Table 19. AC characteristics in Fast-mode and Table 20. AC characteristics in Fast-mode Plus, but the typical time is shorter. The bus controller can implement a polling sequence to utilize this feature.

The sequence, as shown in Figure 17, is:

- Initial condition: A write cycle is in progress.
- Step 1: The bus controller issues a Start condition followed by a device select code (the first byte of the new instruction).
- Step 2: If the device is busy with the internal write cycle, NO ACK is returned and the bus controller goes back to step 1. If the device has terminated the internal write cycle, it responds with an ACK, indicating that the device is ready to receive the second part of the instruction (the first byte of this instruction having been sent during step 1).

Note: When writing a command to the configurable device address register with C2 reconfigured, the device returns ACK only if:

- The chip enable address of the device select code is equal to the new C2 value.
- An internal write cycle is completed (a new C2 value has been programmed in the chip enable register).

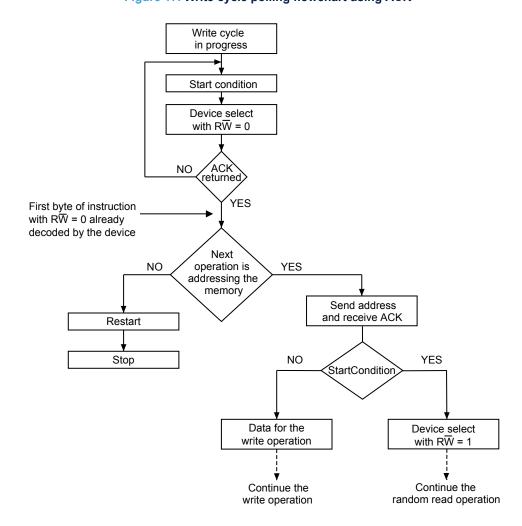


Figure 17. Write cycle polling flowchart using ACK

Note:

The seven most significant bits of the device select code in a random read (bottom right box in the figure above) must match those of the device select code in the write operation (polling instruction).

DS14157 - Rev 3 page 23/55



6.3 ECC (error correction code) and write cycling

ECC is an internal logic function transparent for the I²C communication protocol.

The ECC logic is implemented on each group of four bytes (located at addresses [4*N, 4*N+1, 4*N+2, 4*N+3], where N is an integer). Within a group, if a single bit happens to be erroneous during a read operation, the ECC detects and replaces it with the correct value. The read reliability is therefore much improved.

Even if the ECC function is performed on groups of four bytes, a single byte can be written/cycled independently. In this case, the ECC function also writes/cycles the three other bytes located in the same group. As a consequence, the maximum cycling budget is defined at group level and the cycling can be distributed over the four bytes of the group: the sum of the cycles seen by byte0, byte1, byte2, and byte3 of the same group must remain below the maximum value defined in Table 16. Cycling performance by groups of four bytes.

DS14157 - Rev 3 page 24/55

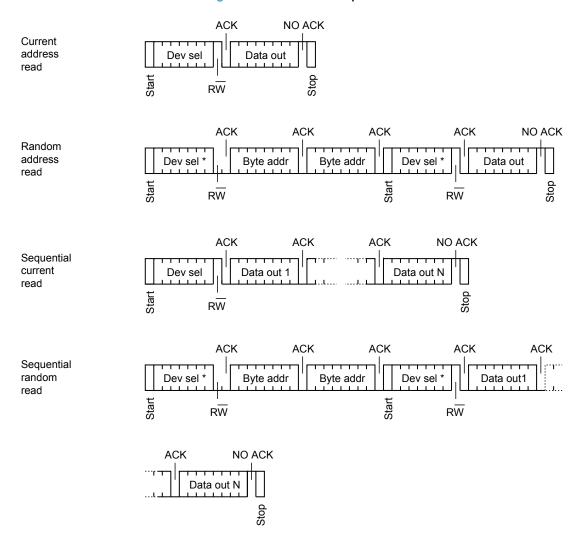
6.4 Read operations on the memory array

Following a start condition the bus controller sends a device select code with the R/W bit $(R\overline{W})$ set to 0. The device acknowledges this and waits for the two-byte address. The device responds to each address byte with an acknowledge bit. Then, the bus controller sends another start condition, and repeats the device select code, with the $R\overline{W}$ bit set to 1. The device acknowledges this, and outputs the contents of the data. See Table 9, Table 10, and Table 11 for how to address the memory array.

After each byte read (data out), the device waits for an acknowledgment (data in) during the ninth bit time. If the bus controller does not acknowledge during this interval, the device terminates the data transfer and switches to its standby mode after a stop condition.

After the successful completion of a read operation, the internal address counter is incremented by one, to point to the next byte address.

Figure 18. Read mode sequences



Note: The seven most significant bits of the first device select code in a random read must match those of the device select code in the write operation.

DS14157 - Rev 3 page 25/55

JT01105dV1



6.4.1 Random address read

A dummy write is first performed to load the address into this address counter (as shown in Figure 18) but without sending a stop condition. Then, the bus controller sends another start condition, and repeats the device select code, with the RW bit set to 1. The device acknowledges this, and outputs the contents of the addressed byte. The bus controller must not acknowledge the byte, and terminates the transfer with a stop condition.

6.4.2 Current address read

For the current <u>address</u> read operation, following a start condition, the bus controller sends only a device select code with the RW bit set to 1. The device acknowledges this and outputs the byte addressed by the internal address counter. The counter is then incremented. The bus controller terminates the transfer with a stop condition, as shown in Figure 18. Read mode sequences, without acknowledging the byte.

Note: The address counter value is defined by instructions accessing either the memory, registers, or the identification page. When accessing the registers or the identification page, the address counter value is loaded with the byte location, therefore the next current address read in the memory uses this new address counter value. When accessing the memory, it is safer to always use the random address read instruction (this instruction loads the address counter with the byte location to read in the memory, see Section 6.4.1: Random address read) instead

6.4.3 Sequential read

of the current address read instruction.

This operation can be used after a current address read or a random address read. The bus controller does acknowledge the data byte output and sends additional clock pulses so that the device continues to output the next byte in sequence. To terminate the stream of bytes, the bus controller must not acknowledge the last byte, and must generate a stop condition, as shown in Figure 18.

The output data comes from consecutive addresses, with the internal address counter automatically incremented after each byte is output. After reaching the last memory address, the address counter rolls over, and the device continues to output data from the memory address 00h.

DS14157 - Rev 3 page 26/55



6.5 Read operations on registers and identification page

6.5.1 Read operation on DTI register

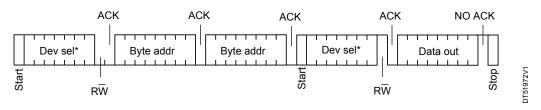
Following a start condition the bus controller sends a device select code with the R/W bit $(R\overline{W})$ set to 0. The device acknowledges this and waits for the address bytes where the DTI register is located. The device responds to each address byte with an acknowledge bit. Then, the bus controller sends another start condition, and repeats the device select code, with the $R\overline{W}$ bit set to 1. The device acknowledges this, and outputs the contents of the DTI register. See in Table 9, Table 10, and Table 11 how to address the device type identifier register.

After the successful completion of a read device type identifier, the device internal address counter is not incremented by one, to point to the next byte address. Reading more than one byte with the sequential random read command loops on reading the device type identifier register value.

To terminate the stream of data byte, the bus controller must not acknowledge the byte, and must generate a stop condition, as shown in Figure 19.

The device type identifier register cannot be read while a write cycle (t_W) is ongoing.

Figure 19. Random read DTI register



Note:

*: The seven most significant bits of the first device select code in a random read must match those of the device select code in the write operation.

DS14157 - Rev 3 page 27/55



6.5.2 Read operation on CDA register

Following a start condition the bus controller sends a device select code with the R/W bit $(R\overline{W})$ set to 0. The device acknowledges this and waits for the address bytes where the CDA register is located. The device responds to each address byte with an acknowledge bit. Then, the bus controller sends another start condition, and repeats the device select code, with the $R\overline{W}$ bit set to 1. The device acknowledges this, and outputs the contents of the CDA register. See in Table 9, Table 10, and Table 11 how to address the configurable device address register.

After the successful completion of a read configurable device address, the device internal address counter is not incremented by one, to point to the next byte address. Reading more than one byte with the sequential random read command loops on reading the configurable device address register value.

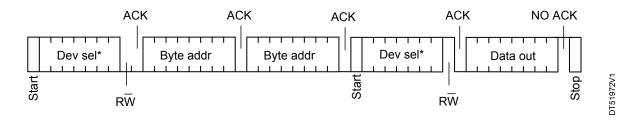
To terminate the stream of data byte, the bus controller must not acknowledge the byte, and must generate a stop condition, as shown in Figure 20.

The configurable device address register cannot be read while a write cycle (t_W) is ongoing.

The value of the configurable device address bit (C2) can be checked by sending the device select code.

- If the chip enable address b3 sent in the device select code matches the C2 value, the device sends an ACK.
- Otherwise, the device answers NO ACK.

Figure 20. Random read CDA register



Note:

*: The seven most significant bits of the first device select code in a random read must match those of the device select code in the write operation.

6.5.3 Read operation on SWP register

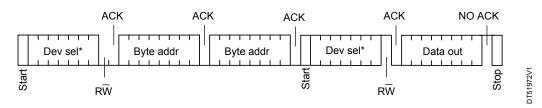
Following a start condition the bus controller sends a device select code with the R/W bit (RW) set to 0. The device acknowledges this and waits for the address bytes where the SWP register is located. The device responds to each address byte with an acknowledge bit. Then, the bus controller sends another start condition, and repeats the device select code, with the RW bit set to 1. The device acknowledges this, and outputs the contents of the SWP register. See in Table 9, Table 10, and Table 11 how to address the software write protection register.

After the successful completion of a read operation on SWP, the device internal address counter is not incremented by one, to point to the next byte address. Reading more than one-byte with the sequential random read command loops on reading the SWP register value.

To terminate the stream of data byte, the bus controller must not acknowledge the byte, and must generate a stop condition, as shown in Figure 21.

The SWP register cannot be read while a write cycle (t_W) is ongoing.

Figure 21. Random read SWP register



Note:

DS14157 - Rev 3 page 28/55

^{*:} The seven most significant bits of the first device select code in a random read must match those of the device select code in the write operation.



6.5.4 Read operation on identification page

Following a start condition the bus controller sends a device select code with the R/W bit (RW) set to 0. The device acknowledges this and waits for the address bytes where the identification page is located. The device responds to each address byte with an acknowledge bit. Then, the bus controller sends another start condition, and repeats the device select code, with the RW bit set to 1. The device acknowledges this, and outputs the contents of the identification page. See Table 9, Table 10, and Table 11 how to address the identification page.

After each byte read (data out), the device waits for an acknowledgment (data in) during the ninth bit time.

The output data of the identification page comes from consecutive addresses, with the internal address counter automatically incremented after each byte output. After the last identification page address (FFh), the address counter rolls-over, and the device continues to output data from identification page address 00h.

To terminate the stream of data byte, the bus controller must not acknowledge the byte, and must generate a stop condition, as shown in Figure 22. Random read identification page.

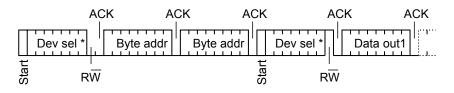
If the bus controller does not acknowledge during this ninth time, the device terminates the data transfer as shown in Figure 22. Random read identification page and switches to its standby mode.

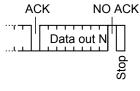
ACK ACK ACK ACK NO ACK Random address Dev sel Byte addr Byte addr Dev sel Data out Start Start Stop $R\overline{W}$ $R\overline{W}$

Figure 22. Random read identification page

Sequential random read

read





Note:

*: The seven most significant bits of the first device select code in a random read must match those of the device select code in the write operation.

DS14157 - Rev 3 page 29/55



6.5.5 Read lock status on identification page

The lock or unlock status of the identification page can be checked by transmitting a specific truncated command. Following a start condition the bus controller sends a device select code with the R/W bit $(R\overline{W})$ set to 0. The device acknowledges this and waits for the address bytes where the identification page is located. The device responds to each address byte with an acknowledge bit, and then waits for the data byte. See in Table 9, Table 10, and Table 11 how to address the identification page.

The device returns an acknowledge bit after the data byte if the identification page is unlocked (unlock status) as shown in Figure 23, otherwise a NO ACK bit as shown in Figure 24, if the identification page is locked (lock status).

Right after this, it is recommended to transmit to the device a start condition followed by a stop condition, so that:

- Start: the truncated command is not executed because the start condition resets the device internal logic
- Stop: the device is then set back into standby mode by the stop condition

Figure 23. Read lock status (identification page unlocked)

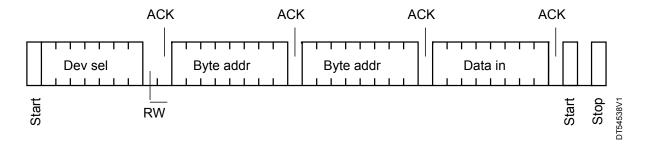
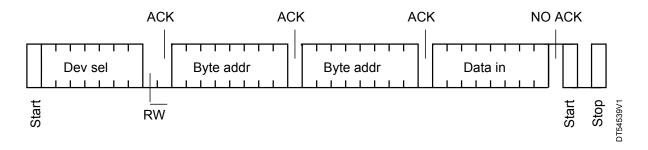


Figure 24. Read lock status (identification page locked)



DS14157 - Rev 3 page 30/55



7 Initial delivery state

At factory delivery, unless a device-specific address has been preprogrammed, the device is delivered with:

- All the memory array bits set to 1 (each byte contains FFh)
- The DTI register locked and set to 10110001 (B1h)
- The CDA register set to 00000000 (00h)
- The SWP register set to 0000000 (00h)
- All the identification page bits set to 1 (each byte contains FFh)

DS14157 - Rev 3 page 31/55



8 Maximum ratings

Stressing the device outside the ratings listed in Table 12 may permanently damage it. These are stress ratings only, and operation of the device at these, or any other conditions outside those indicated in the operating sections of this specification, is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 12. Absolute maximum ratings

Symbol	Parameter	Min.	Max.	Unit
T _A	Ambient operating temperature	-40	130	°C
T _{STG}	Storage temperature	-65	150	°C
T _{LEAD}	Lead temperature during soldering	See note (1)		°C
l _{OL}	DC output current (SDA = 0)	-	5	mA
V _{IO}	Input or output range	-0.50	6.5	V
V _{CC}	Supply voltage	-0.50	6.5	V
V _{ESD}	Electrostatic pulse (human body model) ⁽²⁾	-	4000	V

Compliant with JEDEC standard J-STD-020 (for small body, Sn-Pb or Pb-free assembly), the ST ECOPACK 7191395 specification, and the European directive on restrictions of hazardous substances (RoHS directive 2011/65/EU of July 2011).

DS14157 - Rev 3 page 32/55

^{2.} Positive and negative pulses applied on different combinations of pin connections, according to ANSI/ESDA/JEDEC JS-001 (C1=100 pF, R1=1500 Ω , R2 = 500 Ω).



9 DC and AC parameters

This section summarizes the operating and measurement conditions, and the DC and AC characteristics.

Table 13. Operating conditions

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply voltage	1.6	5.5	V
T _A	Ambient operating temperature	-40	85	°C
f _C	Operating clock frequency	-	1	MHz

Table 14. AC measurement conditions

Symbol	Parameter	Min.	Max.	Unit	
C _{bus}	Load capacitance	-	100	pF	
-	SCL input rise/fall time, SDA input fall time	-	50	ns	
-	Input levels	0.2 V _{CC} to 0.8 V _{CC}		V	
-	Input and output timing reference levels	0.3 V _{CC} t	0.3 V _{CC} to 0.7 V _{CC}		

Figure 25. AC measurement I/O waveform

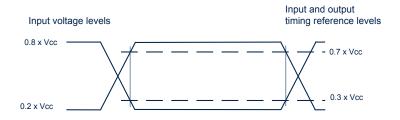


Table 15. Input parameters

Symbol	Parameter	Test condition	Min.	Max.	Unit
C _{IN} ⁽¹⁾	Input capacitance (SDA)	-	-	8	pF
C _{IN} ⁽¹⁾	Input capacitance (other pins)	-	-	6	pF
Z _L ⁽²⁾	land time adepted (MC)(3)	V _{IN} < 0.3 V _{CC}	30	-	kΩ
Z _H ⁽²⁾	Input impedance (WC) ⁽³⁾	V _{IN} > 0.7 V _{CC}	500	-	kΩ

- 1. Specified by design Not tested in production.
- 2. Evaluated by characterization Not tested in production.
- 3. The memory is selected (after a start condition).

DS14157 - Rev 3 page 33/55



Table 16. 0	Cvclina	performance	bν	aroups	of	four by	tes
--------------------	---------	-------------	----	--------	----	---------	-----

Symbol	Parameter	Test condition	Max.	Unit
Novolo	Write cycle endurance ⁽¹⁾	$T_A \le 25 ^{\circ}\text{C}, V_{CC}(\text{min}) < V_{CC} < V_{CC}(\text{max})$	4.000.000	Mrito avala(2)
Ncycle		T _A = 85 °C, V _{CC} (min) < V _{CC} < V _{CC} (max)	1.200.000	Write cycle ⁽²⁾

- 1. The write cycle endurance is defined by characterization and qualification. For devices embedding the ECC functionality, the write cycle endurance is defined for a group of four bytes located at addresses [4*N, 4*N+1, 4*N+2, 4*N+3] where N is an integer.
- 2. A Write cycle is executed when either a page write, a byte write, a write registers, a write identification page or a lock identification page instruction is decoded. When using the byte write, the page write or the write identification page, refer also to Section 6.3: ECC (error correction code) and write cycling.

Table 17. Memory cell data retention

Parameter	Test condition	Min.	Unit
Data retention ⁽¹⁾	T _A = 55 °C	200	Year

^{1.} The data retention behaviour is checked in production, while the data retention limit is extracted from the characterization and qualification results.

Table 18. DC characteristics

Symbol	Parameter	Test conditions	Min.	Max.	Unit
ILI	Input leakage current	$V_{IN} = V_{SS}$ or V_{CC}	-	± 2	μA
	(SCL, SDA)	device in standby mode			
I _{LO}	Output leakage current	SDA in high-Z, external voltage applied on SDA: V_{SS} or V_{CC}	-	± 2	μA
Icc	Supply current (read)	f _C = 400 kHz	-	0.5	mA
100	Supply culterit (read)	f _C = 1 MHz	-	1	mA
I _{CC0}	Supply current (write)	Averaged on t _W , V _{CC} ≤ 3.3 V	-	1.2 ⁽¹⁾	mA
iCC0	Supply current (write)	Averaged on t _W , V _{CC} > 3.3 V	-	2 ⁽¹⁾	IIIA
		Device not selected ⁽²⁾ ,	_	1	μA
I _{CC1}	Standby supply current	$V_{IN} = V_{SS}$ or V_{CC} ; $V_{CC} < 2.5 \text{ V}$	_	'	μΑ
'CC1		Device not selected ⁽²⁾ ,	-	2	μA
		$V_{IN} = V_{SS}$ or V_{CC} ; $V_{CC} \ge 2.5 \text{ V}$			μΑ
V _{IL}	Input low voltage	1.6 V ≤ V _{CC} < 2.5 V	-0.45	0.25 V _{CC}	٧
V IL	(SCL, SDA, WC)	2.5 V ≤ V _{CC} ≤ 5.5 V	-0.45	0.30 V _{CC}	٧
	Input high voltage	1.6 V ≤ V _{CC} < 2.5 V	0.75 V _{CC}	6.5	V
V	(SCL, SDA)	2.5 V ≤ V _{CC} ≤ 5.5 V	0.70 V _{CC}	6.5	V
V _{IH}	Input high voltage	1.6 V ≤ V _{CC} < 2.5 V	0.75 V _{CC}	V _{CC} +0.6	V
	(WC)	2.5 V ≤ V _{CC} ≤ 5.5 V	0.70 V _{CC}	V _{CC} +0.6	V
		I _{OL} = 1 mA, V _{CC} = 1.6 V	-	0.2	V
V _{OL}	Output low	I _{OL} = 2.1 mA, V _{CC} = 2.5 V or			V
		$I_{OL} = 3 \text{ mA}, V_{CC} = 5.5 \text{ V}$	-	0.4	V

^{1.} Evaluated by characterization - Not tested in production.

DS14157 - Rev 3 page 34/55

^{2.} The device is not selected after power-up, after a read instruction (after the stop condition), or after the completion of the internal write cycle t_W (t_W is triggered by the correct decoding of a write instruction).



Table 19. AC characteristics in Fast-mode

Symbol	Alt.	Parameter	Min.	Max.	Unit
f _C	f _{SCL}	Clock frequency	-	400	kHz
t _{CHCL}	t _{HIGH}	Clock pulse width high	600	-	ns
t _{CLCH}	t _{LOW}	Clock pulse width low	1300	-	ns
t _{QL1QL2} ⁽¹⁾	t _F	SDA (out) fall time	20(2)	300	ns
t _{XH1XH2} ⁽¹⁾	t _R	Input signal rise time	(3)	(3)	ns
t _{XL1XL2} ⁽¹⁾	t _F	Input signal fall time	(3)	(3)	ns
t _{DXCH}	t _{SU:DAT}	Data in setup time	100	-	ns
t _{CLDX}	t _{HD:DAT}	Data in hold time	0	-	ns
t _{CLQX} ⁽⁴⁾	t _{DH}	Data out hold time	100	-	ns
t _{CLQV} ⁽⁵⁾	t _{AA}	Clock low to next data valid (access time)	-	900	ns
t _{CHDL}	t _{SU:STA}	Start condition setup time	600	-	ns
t _{DLCL}	t _{HD:STA}	Start condition hold time	600	-	ns
t _{CHDH}	t _{SU:STO}	Stop condition set up time	600	-	ns
t _{DHDL}	t _{BUF}	Time between Stop condition and next Start condition	1300	-	ns
t _{WLDL} ⁽¹⁾⁽⁶⁾	t _{SU:WC}	WC set up time (before the start condition)	0	-	μs
t _{DHWH} ⁽¹⁾⁽⁷⁾	t _{HD:WC}	WC hold time (after the stop condition)	1	-	μs
t _W	t _{WR}	Write cycle time	-	4 ⁽⁸⁾	ms
t _{NS} ⁽¹⁾	-	Pulse width ignored (input filter on SCL and SDA) - single glitch	-	50	ns
t _{WU} ⁽⁹⁾⁽¹⁰⁾	-	Wake up time	-	5	μs

- 1. Evaluated by characterization Not tested in production.
- 2. With $C_L = 10 pF$.
- 3. There is no min. or max. values for the input signal rise and fall times. It is however recommended by the l^2C specification that the input signal rise and fall times be more than 20 ns and less than 300 ns when $f_C < 400$ kHz.
- To avoid spurious start and stop conditions, a minimum delay is placed between SCL = 1 and the falling or rising edge of SDA.
- 5. t_{CLQV} is the time (from the falling edge of SCL) required by the SDA bus line to reach either $0.3V_{CC}$ or $0.7V_{CC}$, assuming that the $R_{bus} \times C_{bus}$ time constant is within the values specified in Figure 26.
- 6. \overline{WC} = 0 setup time condition to enable the execution of a write command.
- 7. \overline{WC} = 0 hold time condition to enable the execution of a write command.
- 8. 3.3 ms typical.
- 9. Specified by design Not tested in production.
- 10. Wake up time: Delay between the $V_{\text{CC}}(\text{min})$ stable and the first accepted command.

DS14157 - Rev 3 page 35/55



Table 20. AC characteristics in Fast-mode Plus

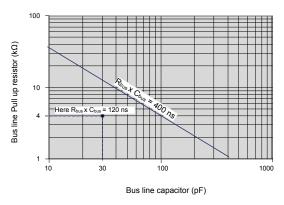
Symbol	Alt.	Parameter	Min.	Max.	Unit
f _C	f _{SCL}	Clock frequency	-	1	MHz
t _{CHCL}	t _{HIGH}	Clock pulse width high	260	-	ns
t _{CLCH}	t _{LOW}	Clock pulse width low	500	-	ns
t _{XH1XH2}	t _R	Input signal rise time	(1)	(1)	ns
t _{XL1XL2}	t _F	Input signal fall time	(1)	(1)	ns
t _{QL1QL2} ⁽²⁾	t _F	SDA (out) fall time	20(3)	120	ns
t _{DXCH}	t _{SU:DAT}	Data in setup time	50	-	ns
t _{CLDX}	t _{HD:DAT}	Data in hold time	0	-	ns
t _{CLQX} ⁽⁴⁾	t _{DH}	Data out hold time	100	-	ns
t _{CLQV} ⁽⁵⁾	t _{AA}	Clock low to next data valid (access time)	-	450	ns
t _{CHDL}	t _{SU:STA}	Start condition setup time	250	-	ns
t _{DLCL}	t _{HD:STA}	Start condition hold time	250	-	ns
t _{CHDH}	t _{SU:STO}	Stop condition setup time	250	-	ns
t _{DHDL}	t _{BUF}	Time between Stop condition and next Start condition	500	-	ns
t _{WLDL} ⁽²⁾⁽⁶⁾	t _{su:wc}	WC set up time (before the start condition)	0	-	μs
t _{DHWH} ⁽²⁾⁽⁷⁾	t _{HD:WC}	WC hold time (after the stop condition)	1	-	μs
t _W	t _{WR}	Write cycle time	-	4 ⁽⁸⁾	ms
t _{NS} ⁽²⁾	-	Pulse width ignored (input filter on SCL and SDA)	-	50	ns
t _{WU} ⁽⁹⁾⁽¹⁰⁾	-	Wake up time	-	5	μs

- 1. There is no min. or max. values for the input signal rise and fall times. It is however recommended by the I^2C specification that the input signal rise and fall times be less than 120 ns when $f_C < 1$ MHz.
- 2. Evaluated by characterization Not tested in production.
- 3. With $C_L = 10 pF$.
- 4. To avoid spurious Start and Stop conditions, a minimum delay is placed between SCL = 1 and the falling or rising edge of
- 5. t_{CLQV} is the time (from the falling edge of SCL) required by the SDA bus line to reach either 0.3 V_{CC} or 0.7 V_{CC}, assuming that the Rbus × Cbus time constant is within the values specified in Figure 27.
- 6. \overline{WC} = 0 setup time condition to enable the execution of a write command.
- 7. $\overline{WC} = 0$ hold time condition to enable the execution of a write command.
- 8. 3.3 ms typical.
- 9. Specified by design Not tested in production.
- 10. Wake up time: Delay between the V_{CC}(min) stable and the first accepted commands.

DS14157 - Rev 3 page 36/55



Figure 26. R_{bus} value versus bus parasitic capacitance (C_{bus}) for an I^2C_{bus} (f_C = 400 kHz)



The R_{bus} x C_{bus} time constant must be below the 400 ns time constant line displayed on the left

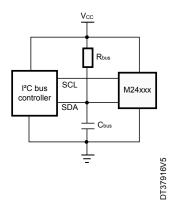
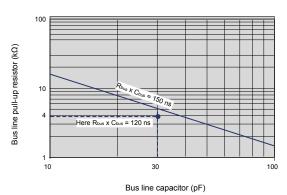
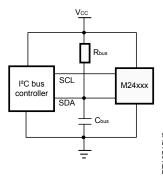


Figure 27. R_{bus} value versus bus parasitic capacitance (C_{bus}) for an I^2C bus ($f_C = 1$ MHz)



The R_{bus} x C_{bus} time constant must be below the 150 ns time constant line displayed on the left

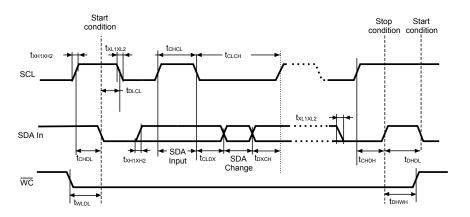


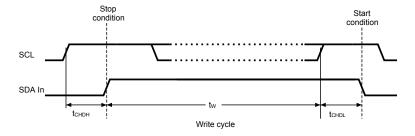
DT19745V8

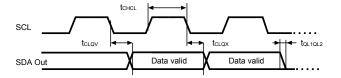
DS14157 - Rev 3 page 37/55



Figure 28. AC waveforms







DT00795iV1



10 Package information

To meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com.

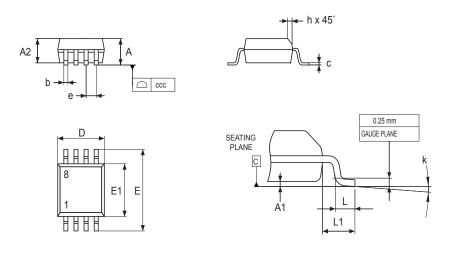
ECOPACK is an ST trademark.

For die information concerning the M24M02E-F delivered in unsawn wafer, contact your nearest ST Sales office.

10.1 SO8N package information

This SO8N is an 8-lead, 4.9 x 6 mm, plastic small outline, 150 mil body width package.

Figure 29. SO8N - Outline



1. Drawing is not to scale.

Z_SO8_ME_V2

DS14157 - Rev 3 page 39/55



Combal		millimeters			inches ⁽¹⁾	
Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.
А	-	-	1.750	-	-	0.0689
A1	0.100	-	0.250	0.0039	-	0.0098
A2	1.250	-	-	0.0492	-	-
b	0.280	-	0.480	0.0110	-	0.0189
С	0.170	-	0.230	0.0067	-	0.0091
D ⁽²⁾	4.800	4.900	5.000	0.1890	0.1929	0.1969
Е	5.800	6.000	6.200	0.2283	0.2362	0.2441
E1 ⁽³⁾	3.800	3.900	4.000	0.1496	0.1535	0.1575
е	-	1.270	-	-	0.0500	-
h	0.250	-	0.500	0.0098	-	0.0197
k	0°	-	8°	0°	-	8°
L	0.400	-	1.270	0.0157	-	0.0500
L1	-	1.040	-	-	0.0409	-
ccc	-	-	0.100	-	-	0.0039

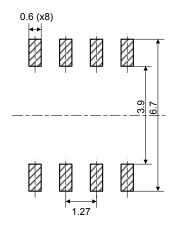
Table 21, SO8N - Mechanical data

- 1. Values in inches are converted from mm and rounded to four decimal digits.
- Dimension D does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side
- 3. Dimension E1 does not include interlead flash or protrusions. Interlead flash or protrusions shall not exceed 0.25 mm per side.

Note:

The package top may be smaller than the package bottom. Dimensions D and E1 are determinated at the outermost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs, and interleads flash, but including any mismatch between the top and bottom of the plastic body. The measurement side for mold flash, protusions, or gate burrs is the bottom side.

Figure 30. SO8N - Footprint example



07_S08N_FP_V2

1. Dimensions are expressed in millimeters.

DS14157 - Rev 3 page 40/55

DT_6P_A_TSSOP8_ME_V4



10.2 TSSOP8 package information

This TSSOP is an 8-lead, 3 x 6.4 mm, 0.65 mm pitch, thin shrink small outline package.

Figure 31. TSSOP8 - Outline

1. Drawing is not to scale.

Table 22. TSSOP8 - Mechanical data

Cumbal		millimeters			inches ⁽¹⁾		
Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	-	-	1.200	-	-	0.0472	
A1	0.050	-	0.150	0.0020	-	0.0059	
A2	0.800	1.000	1.050	0.0315	0.0394	0.0413	
b	0.190	-	0.300	0.0075	-	0.0118	
С	0.090	-	0.200	0.0035	-	0.0079	
D ⁽²⁾	2.900	3.000	3.100	0.1142	0.1181	0.1220	
е	-	0.650	-	-	0.0256	-	
E	6.200	6.400	6.600	0.2441	0.2520	0.2598	
E1 ⁽³⁾	4.300	4.400	4.500	0.1693	0.1732	0.1772	
L	0.450	0.600	0.750	0.0177	0.0236	0.0295	
L1	-	1.000	-	-	0.0394	-	
k	0°	-	8°	0°	-	8°	
aaa	-	-	0.100	-	-	0.0039	

- 1. Values in inches are converted from mm and rounded to four decimal digits.
- 2. Dimension D does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- 3. Dimension E1 does not include interlead flash or protrusions. Interlead flash or protrusions shall not exceed 0.25 mm per side.

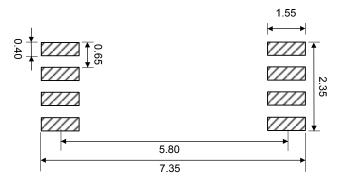
DS14157 - Rev 3 page 41/55



Note:

The package top may be smaller than the package bottom. Dimensions D and E1 are determinated at the outermost extremes of the plastic body exclusive of the mold flash, tie bar burrs, gate burrs, and interleads flash, but including any mismatch between the top and bottom of the plastic body. The measurement side for the mold flash, protrusions, or gate burrs is the bottom side.

Figure 32. TSSOP8 – Footprint example



DT_6P_TSSOP8_FP_V2

1. Dimensions are expressed in millimeters.

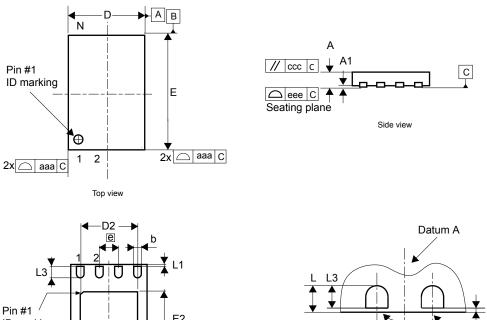
DS14157 - Rev 3 page 42/55



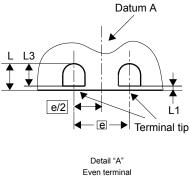
10.3 **UFDFPN8 (DFN8) package information**

This UFDFPN is an 8-lead, 2 x 3 mm, 0.5 mm pitch ultra thin profile fine pitch dual flat package.

Figure 33. UFDFPN8 - Outline



ID marking ND-1 xe See Detail "A" Bottom view



ZWb_UFDFN8_ME_V2

- 1. The maximum package warpage is 0.05 mm.
- 2. Exposed copper is not systematic and can appear partially or totally according to the cross section.
- 3. Drawing is not to scale.
- 4. The central pad (the area E2 by D2 in the above illustration) must be either connected to V_{SS} or left floating (not connected) in the end application.

page 43/55

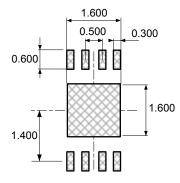


Symbol		millimeters		inches ⁽¹⁾			
Symbol	Min	Тур	Max	Min	Тур	Max	
Α	0.450	0.550	0.600	0.0177	0.0217	0.0236	
A1	0.000	0.020	0.050	0.0000	0.0008	0.0020	
b ⁽²⁾	0.200	0.250	0.300	0.0079	0.0098	0.0118	
D	1.900	2.000	2.100	0.0748	0.0787	0.0827	
D2	1.200	-	1.600	0.0472	-	0.0630	
E	2.900	3.000	3.100	0.1142	0.1181	0.1220	
E2	1.200	-	1.600	0.0472	-	0.0630	
е	-	0.500	-	-	0.0197	-	
K	0.300	-	-	0.0118	-	-	
L	0.300	-	0.500	0.0118	-	0.0197	
L1	-	-	0.150	-	-	0.0059	
L3	0.300	-	-	0.0118	-	-	
aaa	-	-	0.150	-	-	0.0059	
bbb	-	-	0.100	-	-	0.0039	
ccc	-	-	0.100	-	-	0.0039	
ddd	-	-	0.050	-	-	0.0020	
eee ⁽³⁾	-	-	0.080	-	-	0.0031	

Table 23. UFDFPN8 - Mechanical data

- 1. Values in inches are converted from mm and rounded to four decimal digits.
- 2. Dimension b applies to the plated terminal and is measured between 0.15 and 0.30 mm from the terminal tip.
- 3. Applied for exposed die paddle and terminals. Exclude embedding part of the exposed die paddle from measuring.

Figure 34. UFDFPN8 - Footprint example



1. Dimensions are expressed in millimeters.

ZWb_UFDFN8_FP_V2

DS14157 - Rev 3

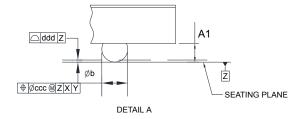


10.4 WLCSP5 (CS) with BSC package information

This WLCSP5 is a 5-ball, 1.570 x 1.862 mm, 0.800 mm pitch, wafer level chip scale package.

DETAIL A e D X Orientation reference BACKSIDE PROTECTION Orientation reference e b A3. aaa (2X) A2 TOP VIEW BUMP VIEW SIDE VIEW

Figure 35. WLCSP5 (CS) with BSC - Outline



E1m_WLCSP5_2M_BSC_ME_V1

- 1. Drawing is not to scale.
- 2. Bump position designation per JESD 95-1, SPP-010.

DS14157 - Rev 3 page 45/55



Table 24. WLCSP5 (CS) with BSC - Mechanical data

Symbol		millimeters		inches ⁽¹⁾			
Зушьог	Min	Тур	Max	Min	Тур	Max	
A ⁽²⁾	0.520	0.555	0.590	0.0205	0.0219	0.0232	
A1	0.180	0.200	0.220	0.0071	0.0079	0.0087	
A2	0.305	0.330	0.355	0.0120	0.0130	0.0140	
A3	-	0.250	-	-	0.0098	-	
Ø b ⁽³⁾⁽⁴⁾	0.250	0.270	0.290	-	0.0106	0.0114	
D	1.550	1.570	1.590	-	0.0618	0.0626	
Е	1.842	1.862	1.882	-	0.0733	0.0741	
е	-	0.800	-	-	0.0315	-	
F	-	0.531	-	-	0.0209	-	
G	-	0.385	-	-	0.0152	-	
Н	-	0.566	-	-	0.0223	-	
N ⁽⁵⁾				5			
aaa	-	-	0.11	-	-	0.0043	
bbb	-	-	0.11	-	-	0.0043	
ccc	-	-	0.11	-	-	0.0043	
ddd	-	-	0.06	-	-	0.0024	

- 1. Values in inches are converted from mm and rounded to four decimal digits.
- 2. A1, A2, and A3 have their own specification. The sum of all of them must comply with the A min and max spec.
- 3. Dimension is measured at the maximum bump diameter parallel to primary datum Z.
- 4. Primary datum Z and seating plane are defined by the spherical crowns of the bump.
- 5. N represents the total number of balls.

DS14157 - Rev 3 page 46/55



10.5 WLCSP5 (CP) with BSC package information

This WLCSP is a 5-ball, 1.572 x 1.864 mm, 0.800 mm pitch, wafer level chip scale package.

Orientation reference

Top view

Side view

Figure 36. WLCSP5 (CP) with BSC - Outline

- 1. Drawing is not to scale.
- 2. Dimension is measured at the maximum bump diameter parallel to primary datum Z.
- 3. Primary datum Z and the seating plane are defined by the spherical crowns of the bump.
- 4. Bump position designation per JESD 95-1, SPP-010.

DS14157 - Rev 3 page 47/55



Table 25. WLCSP5 (CP) - Mechanical data

Complete		Millimeters			Inches ⁽¹⁾			
Symbol	Min	Тур	Max	Min	Тур	Max		
A ⁽²⁾	0.225	0.255	0.285	0.0089	0.0100	0.0112		
A1	-	0.055	0.065	-	0.0022	0.0026		
A2	-	0.175	0.190	-	0.0069	0.0075		
A3	-	0.025	-	-	0.0010	-		
Ø b ⁽³⁾⁽⁴⁾	0.190	0.210	0.230	-	0.0083	0.0091		
D	1.547	1.572	1.597	-	0.0619	0.0629		
E	1.839	1.864	1.889	-	0.0734	0.0744		
е	-	0.800	-	-	0.0315	-		
e1	-	0.500	-	-	0.0197	-		
F	-	0.386	-	-	0.0152	-		
G	-	0.682	-	-	0.0269	-		
N ⁽⁵⁾				5				
aaa	-	-	0.11	-	-	0.0043		
bbb	-	-	0.11	-	-	0.0043		
ccc	-	-	0.11	-	-	0.0043		
ddd	-	-	0.06	-	-	0.0024		
eee	-	-	0.06	-	-	0.0024		

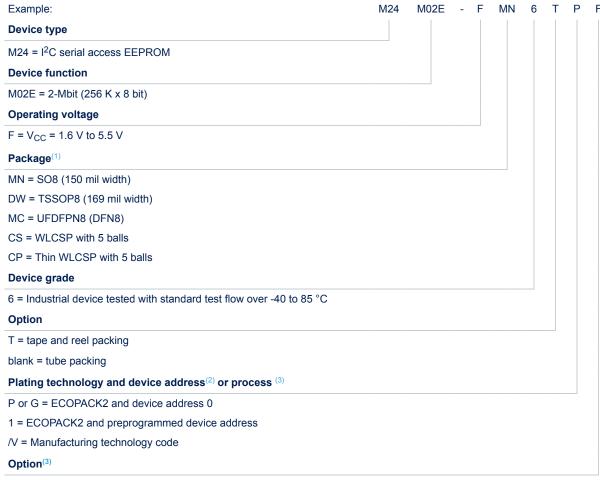
- 1. Values in inches are converted from mm and rounded to four decimal digits.
- 2. A1, A2, and A3 have their own specification. The sum of all of them must comply with the A min and max spec.
- 3. Dimension is measured at the maximum bump diameter parallel to primary datum Z.
- 4. Primary datum Z and seating plane are defined by the spherical crowns of the bump.
- 5. N represents the total number of balls.

DS14157 - Rev 3 page 48/55



11 Ordering information

Table 26. Ordering information scheme



Blank = No back side coating

F = Back side coating

- 1. ECOPACK2 (RoHS compliant and free of brominated, chlorinated and antimony oxide flame retardants).
- 2. See Table 6. Preprogrammed device address.
- 3. For WLCSP only.

Note:

Note: For a list of available options (memory, package, and so on) or for further information on any aspect of this device, contact your nearest ST sales office.

Parts marked as ES or E or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

DS14157 - Rev 3 page 49/55



Revision history

Table 27. Document revision history

Date	Revision	Changes
15-Dec-2023	1	Initial release
29-Aug-2024	2	Updated: Section 10.5: WLCSP5 (CP) with BSC package information Table 26. Ordering information scheme
12-May-2025	3	Updated: Features Section 1: Description Table 6. Preprogrammed device address Table 19. AC characteristics in Fast-mode Table 20. AC characteristics in Fast-mode Plus Section 10.5: WLCSP5 (CP) with BSC package information Added: Unsawn wafer

DS14157 - Rev 3 page 50/55



Contents

1	Des	cription	l 	2
2	Sign	al desc	ription	4
	2.1	Serial	clock (SCL)	4
	2.2	Serial	data (SDA)	4
	2.3	Write	control (WC)	4
	2.4	V _{SS} (g	round)	4
	2.5	Supply	y voltage (V _{CC})	4
		2.5.1	Operating supply voltage (V _{CC})	4
		2.5.2	Power-up conditions	4
		2.5.3	Device reset	4
		2.5.4	Power-down conditions	5
3	Men	nory org	ganization	6
4	Devi	ice feat	ures	7
	4.1	Device	e type identifier register (DTI)	7
	4.2	Config	urable device address register (CDA)	8
	4.3	Softwa	are write protection register (SWP)	9
	4.4	Identif	ication page	10
5	Devi	ice ope	ration	
	5.1	Start c	condition	12
	5.2	Stop c	ondition	12
	5.3	Data ir	nput	12
	5.4	Ackno	wledge bit (ACK)	12
	5.5	Device	e addressing	13
6	Insti	ructions	S	15
	6.1	Write	operations on memory array	15
		6.1.1	Byte write	16
		6.1.2	Page write	17
	6.2	Write o	operations on registers, identification page, and minimizing delays	18
		6.2.1	Write operation on DTI register	18
		6.2.2	Write operation on CDA register	18
		6.2.3	Write operation on SWP register	
		6.2.4	Write operation on identification page	
		6.2.5	Lock operation on identification page	
		6.2.6	Minimizing write delays by polling on ACK	23

Contents



	6.3	ECC (ECC (error correction code) and write cycling24						
	6.4	Read	operations on the memory array	25					
		6.4.1	Random address read	26					
		6.4.2	Current address read	26					
		6.4.3	Sequential read	26					
	6.5	Read	operations on registers and identification page	27					
		6.5.1	Read operation on DTI register	27					
		6.5.2	Read operation on CDA register	28					
		6.5.3	Read operation on SWP register	28					
		6.5.4	Read operation on identification page	29					
		6.5.5	Read lock status on identification page	30					
7	Initia	ıl deliv	ery state	31					
8	Maxi	mum r	atings	32					
9	DC a	nd AC	parameters	33					
10	Pack	age in	formation	39					
	10.1	SO8N	I package information	39					
	10.2	TSSO	P8 package information	41					
	10.3	UFDF	PN8 (DFN8) package information	43					
	10.4	WLCS	SP5 (CS) with BSC package information	45					
	10.5	WLCS	SP5 (CP) with BSC package information	47					
11	Orde	ring in	nformation	49					
Rev	ision	historv	/	50					



List of tables

Table 1.	Signal names	. 2
Table 2.	Device type identifier register	. 7
Table 3.	Device type identifier register description	. 7
Table 4.	Configurable device address register	. 8
Table 5.	Configurable device address register description	. 8
Table 6.	Preprogrammed device address	. 9
Table 7.	Software write protection register values	. 9
Table 8.	Software write protection register description	10
Table 9.	Device select code	13
Table 10.	First byte address	13
Table 11.	Second byte address	14
Table 12.	Absolute maximum ratings	32
Table 13.	Operating conditions	33
Table 14.	AC measurement conditions	33
Table 15.	Input parameters	33
Table 16.	Cycling performance by groups of four bytes	34
Table 17.	Memory cell data retention	34
Table 18.	DC characteristics	34
Table 19.	AC characteristics in Fast-mode	35
Table 20.	AC characteristics in Fast-mode Plus	36
Table 21.	SO8N - Mechanical data	40
Table 22.	TSSOP8 - Mechanical data	
Table 23.	UFDFPN8 - Mechanical data	
Table 24.	WLCSP5 (CS) with BSC - Mechanical data	46
Table 25.	WLCSP5 (CP) - Mechanical data	48
Table 26.	Ordering information scheme	49
Table 27.	Document revision history	50



List of figures

Figure 1.	Logic diagram	2
Figure 2.	8-pin package connections, top view	3
Figure 3.	5-ball package connection - WLCSP (CS)	3
Figure 4.	5-ball package connection- WLCSP (CP)	3
Figure 5.	Block diagram	6
Figure 6.	I ² C bus protocol	11
Figure 7.	Write mode sequences without write protection (data write enabled)	16
Figure 8.	Write mode sequences with write protection (data write inhibited)	17
Figure 9.	Write CDA register (data write enabled)	18
Figure 10.	Write CDA register (data write inhibited by software or hardware)	18
Figure 11.	Write SWP register (data write enabled)	19
Figure 12.	Write SWP register (data write inhibited by software or hardware)	19
Figure 13.	Write identification page (page unlocked)	20
Figure 14.	Write identification page (page locked or hard protected)	21
Figure 15.	Lock operation on identification page (unlocked or data write enabled)	22
Figure 16.	Lock operation on identification page (already locked or data write inhibited by hardware)	22
Figure 17.	Write cycle polling flowchart using ACK	23
Figure 18.	Read mode sequences	25
Figure 19.	Random read DTI register	27
Figure 20.	Random read CDA register	28
Figure 21.	Random read SWP register	28
Figure 22.	Random read identification page	29
Figure 23.	Read lock status (identification page unlocked)	30
Figure 24.	Read lock status (identification page locked)	30
Figure 25.	AC measurement I/O waveform	33
Figure 26.	R_{bus} value versus bus parasitic capacitance (C_{bus}) for an I^2C_{bus} (f_C = 400 kHz)	37
Figure 27.	R_{bus} value versus bus parasitic capacitance (C_{bus}) for an I^2C bus (f_C = 1 MHz)	
Figure 28.	AC waveforms	
Figure 29.	SO8N - Outline	39
Figure 30.	SO8N - Footprint example	40
Figure 31.	TSSOP8 – Outline	41
Figure 32.	TSSOP8 – Footprint example	42
Figure 33.	UFDFPN8 - Outline	43
Figure 34.	UFDFPN8 - Footprint example	
Figure 35.	WLCSP5 (CS) with BSC - Outline	45
Figure 36.	WLCSP5 (CP) with BSC - Outline	47

DS14157 - Rev 3 page 54/55



IMPORTANT NOTICE - READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgment.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, refer to www.st.com/trademarks. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2025 STMicroelectronics – All rights reserved

DS14157 - Rev 3 page 55/55